## Topological order in the insulating Josephson junction array.

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W e propose a Josephson junction array which can be tuned into an unconventional insulating state by varying external magnetic eld. This insulating state retains a gap to half vortices; as a consequence, such array with non-trivial global geom etry exhibits a ground state degeneracy. This degeneracy is protected from the e ects of external noise. W e com pute the gaps separating higher energy states from the degenerate ground state and we discuss experiments probing the unusual properties of this insulator.

A device im plem enting an ideal quantum com puter would be a very interesting object from a physics point of view: it is a system with exponentially many degenerate states (N Ź,K 10<sup>4</sup>) and extrem ely low decoherence rate<sup>1</sup>. The latter implies that the coupling of these states to the noise eld produced by environment should be very small, more precisely all states are coupled to the external noise in exactly the same way:  $\ln \phi mi = O_{0 mn} + o(e^{L})$  where  $\phi$  is an operator of the physical noise and L is a parameter such as the system size that can be made as large as desired. This condition is naturally satis ed<sup>2</sup> if degenerate states are distinguished only by a non-local topological order parameter.<sup>3,4</sup>. In the previous work<sup>5</sup> we have proposed a superconducting Josephson junction array that, in addition to superconducting long range order, acquires a topological order param eter for the arrays with nontrivial geom etry. The goal of this paper is to identify the Josephson junction array with the ground state characterized only by the topological order parameter and no other long range order of any other kind (in local variables) and which has a gap to all other (non-topological) excitations. Because such array has neither superconducting phase sti ness nor gapless excitations it can not carry an electric current; thus in the following we shall call it topological insulator. W hile the arrays with sim ilar global properties were proposed and studied in a recent work<sup>6</sup>, the arrays discussed here have a num ber of in portant practical advantages which makes them more feasible to built and measure in laboratory.

In physical terms, the topological superconductor appearing in the array<sup>5</sup> is a super uid of 4e composite objects. The topological degeneracy of the ground state arises because 2e excitations have a gap. Indeed, in such system with the geometry of an annulus, one extra C ooper pair injected at the inner boundary can never escape it; on the other hand, it is clear that two states di ering by the parity of the num ber of C ooper pairs at the boundary are practically indistinguishable by a local m easurem ent.

G enerally, increasing the charging energy in a Josephson junction array m akes it an insulator. This transition

is due to an increase of phase uctuations in the original array and the resulting appearance of free vortices that form a super uid of their own. The new situation arises in topological superconductor because it allows half-vortices. Two scenarios are now possible. The "conventional" scenario would involve condensation of half-vortices since they are conjugate to 4e charges. In this case we get an insulator with elementary excitations carrying charge 4e. An alternative is condensation of full vortices (pairs of half vortices) with a nite gap to half vortices. In this case the elementary excitations are charge 2e ob jects. Sim ilar fractionalization was discussed in the context of high  $T_{\rm c}$  superconductors  ${\rm in}^{7,8}$  and in the context of spin or quantum dimer system s in<sup>9,10,11,12,13</sup>. Such insulator acquires interesting topological properties on a lattice with holes because each hole leads to a new binary degree of freedom which describes presence or absence of half vortex. The energies of these states are equal up to corrections which vanish exponentially with the size of the holes. These states cannot be distinguished by localm easurem ents and have all properties expected for a topological insulator. They can be measured, however, if the system is adiabatically brought into the superconductive state by changing som e controlling param eter. In this paper we propose a modi cation of the array  $^{5}$  that provides such control param eter and, at the sam e time, allows us to solve the model and compute the properties of the topological insulator.

The main physical idea of the array is to give a system where kinetic energy of half vortex, thy is param etrically sm aller than the kinetic energy of the full vortex,  $t_{fv}$  and where their potential energies, W , satisfy  $t_{hv} < W < t_{fv}$ . The array is shown in Fig. 1, it contains rhom biwith junctions characterized by Josephson and charging energies  $E_J > E_C$  and weak junctions with  $_J$ С E<sub>C</sub>. Each rhom bus encloses half of a ux quantum leading to an exact degeneracy between the two states of opposite chirality of the circulating current<sup>5,14</sup>. This degeneracy is a consequence of the sym m etry operation which com bines the relection about the long diagonal of the rhom bus and a gauge transform ation needed to com pensate the change of the ux  $_0=2!$  $_0=2$ . This gauge transform ation

changes the phase di erence along the diagonal by . This  $Z_2$  symmetry in plies the conservation of the parity of the number of pairs at each site of the hexagonal lattice and is the origin of the Cooper pair binding. We assume that each elementary hexagon contains exactly k weak junctions: in case each link contains one weak junction k = 6, but generally it can take any value k 1. A s will be shown below, the important condition is the number of weak junctions that one needs to cross in the elementary loop. Qualitatively, a value k 1 ensures that it costs a little to put vortex in any hexagon.

For the general argum ents that follow below the actual construction of the weak links is not in portant, how ever, practically it is di cult to vary the ratio of the capacitance to the Josephson energy so weaker Josephson contact usually in plies larger C culom b energy. This can be avoided if weak contact is made from Josephson junction loop frustrated by magnetic eld. The charging energy of this system is half the charging energy of the individual junction while the eld ective Josephson junction strength is  $J = 2 - \frac{0}{0} E_0$  where  $E_0$  is the Josephson energy of each contact and  $= -\frac{0}{2}$  is the difference of the ux from half ux quanta. This construction also allow s to control the system by varying the magnetic eld.

A ssume that  $_{\rm J}$  sets the lowest energy scale in this problem (the exact condition will be discussed below). The state of the array is controlled by discrete variables  $u_{ab} = 0;1$  which describe the chiral state of each rhom bus and by continuous phases  $_{ab}$  that specify the state of each weak link (here and below a; b denote the sites of hexagonal lattice). If Josephson coupling  $_{\rm J}$  0 di erent islands are completely decoupled and potential energy does not depend on discrete variables  $u_{ab}$ . For sm all  $_{\rm J}$  we can evaluate its e ect in the perturbation theory:

$$V(\mathbf{u}) = \mathbf{W} \cos(\sum_{hex}^{X} u_{ab}); \mathbf{W} = \frac{\mathbf{k}^{k}}{k!} \frac{\mathbf{J}}{\mathbf{g}_{c}} \int_{\mathbf{J}}^{k-1} \mathbf{J}$$
(1)

This potential energy lowers the energy of classical congurations of  $u_{ab}$  that satisfy the constraint  $u_{bex} u = 0$  [2] but does not prohibit the ones with  $u_{bex} u = 1$  [2].

Consider now the dynam ics of discrete variables. Generally, two types of tunneling processes are possible. In the rst type the phase changes by across each of the three rhom bit hat have a common site. This is the sam e process that gives the leading contribution to the dynam – ics of the superconducting array<sup>5</sup>, its am plitude is given (in the quasiclassical approxim ation) by

r 
$$E_{J}^{3=4}E_{C}^{1=4}\exp(3S_{0}); S_{0} = 1:61^{p} \overline{E_{J}=E_{C}}$$
 (2)

In the second type of process the phase changes across one rhombus and across one weak junction. Because the potential energy of the weak junction is assumed to be very small the main e ect of the weak junction is to change the kinetic energy. The total kinetic energy for this process is the sum of the term s due to the phase across the rhom bi and across the weak link. A s-

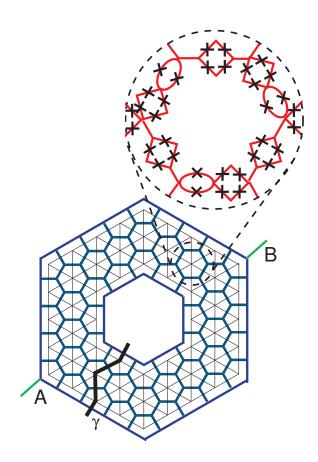


FIG.1: Schematics of the array. The main gure: global structure of the array. D iscrete variables controlling the low energy properties are de ned on the links of the hexagonal lattice. Generally, the lattice m ight have K big holes, here we show K = 1 example. Zoom in: Each inner bond of the lattice contains a rhom bus m ade out of four Josephson junctions; som e bonds also contain an e ective weaker link m ade of two Josephson junctions so that each hexagon of the lattice contains k = 3 such links. The ux through each rhom bus is half-ux quanta,  $_0=2$ , the ux through a loop constituting a weak link is close to half ux quanta =  $_0=2+$ . The boundary of the lattice contains rhom bi and weak links so that each boundary plaquette has the same number, k, of weak links as the bulk hexagon.

sum ing that these phase variations are equal and opposite in sign, the form er is about  $E_c^{1} - 2$  while the latter  $_{\rm c}^{-1}$   $^{-2}$ , so the elective charging energy of this process is  $\vec{E}_{c} = E_{c}^{1} + C_{c}^{1}$ . For  $c = E_{c}$  this charging energy is small and such process is suppressed. Thus, in these conditions the dom inating process is the simultaneous ip of three rhom bias in the superconducting case. In the following we restrict ourselves to this case. Further, we shall assume that r W so that in the leading order one can neglect the potential energy com pared to the kinetic energy corresponding to the ip of three rhom bi. AsW is increased by turning on J the continuous phase ab orders and the transition into the superconducting state happens at J C. At larger J, W becomes J and with a further increase of  $_{\rm J}$ , for  $_{\rm J}$ r vortices com pletely disappear from the low energy spectrum and the array becomes equivalent to the one studied  $in^5$ .

The low energy states are the ones that m inim ize the kinetic energy corresponding to simultaneous ip processes:

$$H_{T} = r \qquad \begin{array}{c} X & Y \\ a & ab \\ a & b(a) \end{array}$$
(3)

Here b(a) denote the nearest neighbors of site a,  $ab^{x}_{ab}$  is the operator that ips discrete variables  $u_{ab}$  and r is given by (2). The states m in in izing this energy satisfy the gauge invariance condition

The Hilbert space of states that satisfy the condition (4) is still huge. If all weaker term s in the H am iltonian are neglected all states that satisfy (4) are degenerate. These states can be visualized in terms of half vortices positioned on the sites of the dual lattice, i; j. Indeed, a convenient way to describe di erent states that satisfy (4) is to note that operator  $\begin{bmatrix} x \\ b(a) \end{bmatrix}$  does not change the value of  $j_{(i)}$  u [2]. Thus, one can x the values of  $u_{ij} = v_i$  on all plaquettes, i and in pose the constraint (4). In physical terms the binary values  $v_i = 0;1$ describe the positions of half-vortices on dual lattice. This degeneracy between di erent states is lifted when the subdom inant term s are taken into account. Them ain contribution to the potential energy of these half-vortices com es from (1), it is simply proportional to their num ber. The dynamics of these vortices is due to the processes in which only one rhombus changes its state and the corresponding ip of the phase accross the weak junction. The amplitude of this process is

$$\mathbf{e} \quad \mathbf{E}_{J}^{3=4} \mathbf{E}_{C}^{1=4} \exp(\mathbf{5}_{0}); \ \mathbf{5}_{0} = 1:61 \quad \frac{\mathbf{E}_{J}}{\mathbf{E}_{C}}$$

The e ective H am iltonian of half-vortices is

$$H_{v} = e_{ji} X X_{i} X_{ji}$$

$$H_{v} = H_{v} X_{i}$$

$$H_{v} = H_{v}$$

$$H_{v} = H_{v} X_{i}$$

$$H_{v} = H_{v} X_$$

where operators  $_{i}$  act in the usual way on the states with/without half-vortices at plaquette i and the rst sum runs over adjacent plaquettes (ij). This Ham iltnian describes an Ising model in a transverse edd. For small  $W = e < _{c}$  1 its ground state is "disordered": h<sup>2</sup>i = 0 but h<sup>×</sup>i  $\in$  0 while for  $W = e > _{c}$  it is "ordered": h<sup>2</sup>i  $\in$  0, h<sup>×</sup>i = 0. The critical value of transverse edd is known from extensive num erical simulations<sup>15</sup>: \_{c} 4:6 0:3 for triangular lattice. The "disordered" state corresponds to the liquid of half-vortices, while in the "ordered" state the density of free half-vortices vanishes, i.e. the ground state contains even number of half-vortices so the total vorticity of the system is zero. To prove this we start from the state j"i which is the ground state at e = W = 0 and

consider the e ect of  $\mathbf{e}^{i}_{(ij)}$ ,  $\mathbf{e}^{i}_{j}$  in perturbation theory. Higher energy states are separated from the ground state by the gap W so each order is nite. Further in each order operator  $\mathbf{e}^{i}_{j}$  create twom ore half-vortices proving that the total number of half-vortices remains even in each order. The states with odd number of half-vortices have a gap ( $\mathbf{e}=W$ ) which remains non-zero for  $W = \mathbf{e} > c$ .

In term s of the original discrete variable de ned on the rhom bithe H am iltonian (5) becomes

$$H_{u} = \underbrace{\begin{array}{cccc} X & X & Y \\ e & ij & W & ij \\ (ij) & i j(i) \end{array}}_{(ij)} (6)$$

where operators act on the state of each rhom bus. This H am iltonian commutes with the constraint (4) and is in fact the simplest H am iltonian of the lattice  $Z_2$  gauge theory. The disordered regime corresponds to a conned phase of this  $Z_2$  gauge theory, leading to elementary 4e charge excitations and the ordered regime to the deconned phase.

C onsider now the system with non-trivial topology, e.g. a hole. In this case the set of variables  $v_i$  is not su cient to determ ine uniquely the state of the system, one has to supplement it by the variable  $v_0 = \int_L u_{ij}$  where sum is taken over a closed contour L that goes around the hole. Physically, it describes the presence/absence of the half-vortex in the hole. The elective H am iltonian of this additional variable has only kinetic part because presence or absence of half vortex in a hole which has lweak links in its perimeter gives potential energy W<sub>0</sub> = c<sub>J</sub>  $\frac{J}{c}$ 

which is exponentially small for  $1 - 1_p$  The kinetic part is similar to other variables:  $H_0 = e_{i2I} \stackrel{x}{i} \stackrel{x}{}_{0}$ ; it describes a process in which half-vortex jumps from the hole into the inner boundary, I, of the system . In the state with h z i  $\in$  0 this process increases the energy of the system by  $\widetilde{W}$  ( $\frac{W}{e}$ ) ( $\widetilde{W}$  (0) = W and  $\widetilde{W}$  (<sub>c</sub>) = 0). In the state with h <sup>x</sup>i = 0 it costs nothing. Thus, the process in which half-vortex jumps from the hole into the system and another half-vortex exits into the outside region appears in the second order of the perturbation theory, the amplitude of this process is  $t_v = e^{2^{t}}$   $_{i2I;j20} g_{ij}$  where sum is performed over all sizes of the inner (I) and outer (0) boundaries and  $g_{ij} = \sum_{i=H-E_0}^{x} \frac{1}{i_{H-E_0}} x_{j}$  has a physical meaning of the half vortex tunneling amplitude from inner to outer boundaries. At sm all -W, we can estim ate  $q_{ij}$  using the perturbation expansion in e=W: the leading contribution appears in ji jth order of the perturbation theory, thus  $g_{ij} / (e=W)^{ji}$ . Thus for small EW the tunneling am plitude of the half vortex is exponentially sm all in the distance, L, from the outer to the inner boundary; we expect that it rem ains exponentially smallforalle=W < c.Fore=W > c this amplitude is of the order of  $e^2 = W$  and therefore is signi cant.

In a di erent language, in the system with a hole we can construct a topological invariant  $P = \sum_{ij}^{x} (con-tour)$  is shown in Fig. 1) which can take values 1. The same arguments as used for the superconducting ar-

ray show that any dynam ics consistent with constraint (4) preserves P. Thus, form ally, the properties of the topological insulator are very sim ilar to the properties

of the topological superconductor discussed in<sup>5</sup>, if one replaces the words C ooper pair by half-vortex and vice versa. W e sum marize this duality in the following table

	Topological Superconductor	Topological Insulator
G round state	Condensate of 4e charges	Condensate of 2 phase vortices
Fluxons	G apful, charge 2e	Gapful, phase vortices
P seudocharges	Half uxes with energy $E_{\rm J}$ log	(L) Charge 2e with = $2r_{\cdot}^{17}$
G round state degeneracy	Charge on the inner boundary mo	d 4e Number of vortices inside the hole m od 2
G round state splitting	$\left(-\frac{E_J}{r}\right)^L$	(æ≕W) <sup>⊥</sup>
	ŭ	

Note that at small e=W ! 0 the ground state of the Ham iltonian (6) satis es the condition (4) and minip izes the second term in (6), i.e. satis es the condition  $Q_{j(i)} \stackrel{z}{ij} j = ji$ ; it can be explicitly written as  $j = Q_{i\frac{1}{2}}(1 + \sum_{j(i)} Q_{ij})_{kl} j! i_{k1}$ . This state is a linear superposition  $\frac{1}{2}(j+i+j)$  i) of the degenerates states with P = 1 and P = 1; it coincides with the ground state of discrete variables in the superconducting array. The orthogonal superposition of P = 1 states,  $\frac{1}{2}(j+i+j)$ ; or responds to the half-vortex inside the hole and has a m uch larger energy in the superconductive array.

The degenerate ground states in the insulating array can be manipulated in the same way as in the superconductor. Since physically these states correspond to the absence or presence of the half-vortex inside the hole the adiabatic change of local magnetic eld that drags one half vortex across the system, ips the state of the system, providing us with the implementation of the operator  $^{\rm X}$  acting on the state of the qubit. A nalogously, motion of elementary charge 2e around the hole changes the relative phase of the states with and without half-vortex providing us with the operator  $^{\rm Z}$ .

The signature of the topological insulator is the persistence of the trapped half ux inside the central hole (see Fig. 1) which can be observed by cycling magnetic eld so as to drive the system back and forth between

insulating and superconducting states. This trapping is especially striking in the insulator. Experimentally, this can be revealed by driving slow ly the array into a superconducting state and then m easuring the phase di erence between opposite points such as A and B in Fig. 1. In the state with a half vortex the phase di erence is =2 + nwhile it is n in the other state. The n contribution is due to the usual vortices that get trapped in a big hole. This slow transform ation can be achieved by changing the strength of weak links using the external magnetic eld as a control parameter. The precise nature of the superconductive state is not essential because phase difference between points A and B can be interpreted as due to a full vortex trapped in a hole in a convertional superconductor or due to a periodicity in a topologicalone which makes no essential di erence. These ux trapping experiments are similar to the ones proposed for high-T<sub>c</sub> cuprates<sup>8,16</sup>w ith a num ber of im portant differences: the trapped ux is half of 0, the cycling does not involve tem perature (avoiding problem swith excitations) and the nal state can be either conventional or topological superconductor.

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- <sup>17</sup> We neglect here the contributions proportional to <sub>c</sub>: <sub>c</sub> m in [log L; log (c=c<sub>0</sub>)] where c is the capacitance of a weak link and c<sub>0</sub> is the self-capacitance of an island.